

PRODUCT DATASHEET

DESCRIPTION	KEY FEATURES
<p>The PD70101A and PD70201 are integrated Powered Device Interface and PWM controllers for a DC-DC converter used in IEEE802.3af and IEEE802.3at applications. The PD70101A can be used for IEEE802.3af or IEEE802.3at Type 1 applications, while the PD70201 can also be used in IEEE802.3at Type 2 applications.</p> <p>A single PD70201 can be used in 4-pair applications which consumes up to 47.7W.</p> <p>These devices have a number of features designed to improve efficiency and reliability:</p> <p>Detection and Classification: The front end interface includes detection and classification circuitry. The detection signature resistor is disconnected upon completion of the detection phase. The system then begins the classification phase. Classification can be configured for Classes 0 to 4 via an external resistor. The PD70201 includes a two-events classification identification circuit which generates a flag to inform the PD application whether the Power Source Equipment (PSE) is Type 1 or Type 2.</p> <p>Capacitor: A current limited internal MOSFET switch charges the input capacitor of the DC-DC converter. This capacitor is discharged in a timely manner when the input power is removed.</p> <p>10V Gate drivers: The PWM DC-DC controller has two built-in minimum 10V gate drivers targeted for flyback, forward converter with secondary synchronous rectifier or direct buck. The gate drivers lower external Power MOSFET power loss while offering a wider MOSFET selection.</p> <p>Peak current mode control: The DC-DC converter employs peak current mode control for better line and load step response. The switching frequency can be set from 100 kHz to 500 kHz, enabling a size and efficiency trade off.</p>	<p>Maximum duty cycle is limited to 50% to reduce the power MOSFET switch voltage to two times the input voltage; a 150V rated MOSFET can be used for the primary side switch. The secondary synchronous MOSFET voltage rating depends on the output voltage and can be higher or lower than the primary side MOSFET switch.</p> <p>Soft-start circuit: The devices include a soft-start circuit to control the output voltage rise time (user settable) at start up, and to limit the inrush current. An integrated start-up bias circuit powers the DC-DC controller, until the device starts up by the voltage generated by the bootstrap circuit.</p> <p>Low Voltage Protection Warning and Monitoring: Dual Under Voltage Lock Out (UVLO), which monitors both the PoE Port Input Voltage and VCC, ensures reliable operation during any system disturbances. The PoE port UVLO has a programmable threshold and hysteresis to enable tailoring to the desired turn on and turn off voltage.</p> <p>An internal current sense amplifier with a Kelvin connection allows the use of an extremely low resistor to measure the current sense threshold voltage (200 mV) which optimizes efficiency.</p> <p>Low Power Mode operation is provided to improve efficiency under light loads such as when the PD is in standby. The user can define at what power level the unit enters low power mode by means of a single resistor value.</p>
IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com	

APPLICATIONS

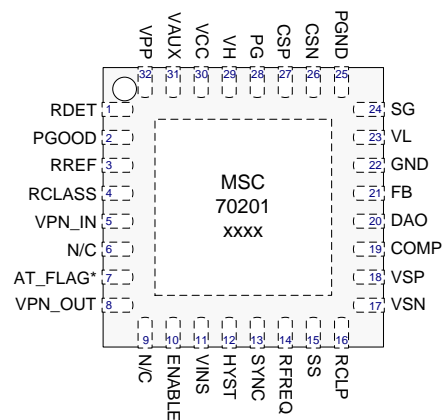
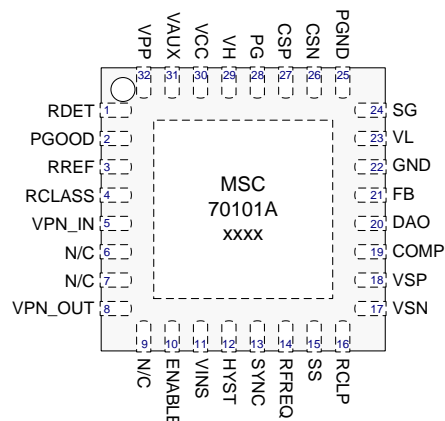
- IEEE802.3at and IEEE802.3af Powered Devices Such as IP Phones, WLAN Access points and network cameras.
- 48V Input Telcom/Networks Hot Swappable Power Supply

PRODUCT DATASHEET
ABSOLUTE MAXIMUM RATINGS

VPP, RDET, VPN_OUT (with respect to VPN_IN)	-0.3V to 74V _{DC}
RREF, RCLASS (with respect to VPN_IN)	-0.3V to 6V
PGOOD, AT_FLAG, VAUX (with respect to VPN_OUT)	-0.3V to 74V
VCC (with respect to PGND)	-0.3V to 40V _{DC}
PG, SG (with respect to PGND)	-0.3V to 20V _{DC}
VL (with respect to PGND)	-0.3V to 6V _{DC}
VH (with respect to VCC)	-0.3V to VCC - 6V _{DC}
All Other Pins (with respect to GND)	-0.3V to VL + 0.3V _{DC}
Maximum Operating Junction Temperature	150°C
Operating Ambient Temperature	-40°C to 85°C
ESD Protection at all I/O pins*	± 1KV HBM
Storage Temperature Range	-65°C to 150°C
Peak Package Solder Reflow Temp (40 seconds max exposure)	260°C

*All pins except pin 2 (PGOOD) and pin 31 (VAUX). Pin 2 & 31 ESD Protection ±150V HBM.

Notes: Exceeding these ratings could cause damage to the device. All voltages are with respect to VPN_{IN}. Currents are positive into, negative out of specified terminal. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" are not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

PACKAGE PIN OUT


QFN PACKAGE
(Top View)

RoHS / Pb-free 100% matte Tin Pin Finish
xxxx = Date code / Lot code

PACKAGE ORDER INFO
THERMAL DATA

T _A (°C)	LQ	5x5 Plastic QFN 32 pin	$\theta_{JA} = 23^{\circ}\text{C/W}$ $\theta_{JC} = 4^{\circ}\text{C/W}$
		RoHS Compliant / Pb-free	THERMAL RESISTANCE-JUNCTION TO AMBIENT
-40 to +85		PD70101AILQ (IEEE802.3af) PD70201ILQ (IEEE802.3at)	Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$. The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow. θ_{JA} number above is with 4-layer PCB board with 9 thermal vias.
Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. PD70201ILQ-TR)			

ELECTRICAL CHARACTERISTICS

Unless otherwise specified, the following specifications apply over the operating ambient temperature of $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ except where otherwise noted with the following test conditions: $V_{PP} = 48\text{V}$; $V_{EN} = \text{HIGH}$, $f_s = 250\text{ kHz}$. Production tests performed at 25°C . Unless otherwise specified V_{PP} is with respect to VPN_IN , VCC is with respect to $PGND$.

Parameter	Symbol	Test Conditions / Comment	PD70101A & PD70201			Units
			Min	Type	Max	
PD Interface						
POWER SUPPLY						
Input Voltage	V _{PP}		0	55	57	V
DETECTION MODE						
Detection Voltage Range.	DET _{RANGE}	Measured between V _{PP} and V _{PNIN}	1.3		10.1	V
Detection Switch ON Resistance	R _{DET-on}	2.5V ≤ (ΔV _{PP} to V _{PNIN}) ≤ 10.1V Measured between R _{DET} and V _{PNIN}			50	Ω
Detection is Disconnected	R _{DET-off}	Measured between V _{PP} and V _{PNIN}	10.1		12.8	V
Detection switch OFF resistance	R _{DET-off}	12.8V ≤ (ΔV _{PP} to V _{PNIN}) ≤ 57.0V Measured between R _{DET} and V _{PNIN}	2.0			MΩ
Input offset current	I _{OFFSET}	2.5V ≤ V _{PP} ≤ 10.1V -40°C ≤ T _J ≤ 85°C			16	μA
	I _{OFFSET}	2.5V ≤ V _{PP} ≤ 10.1V -40°C ≤ T _J ≤ 55°C			10	μA
RDET reconnection level	V _{RDET-on}	Measured between V _{PP} and V _{PNIN}	1.95	3.0	4.85	V
CLASSIFICATION MODE						
Classification Current Source, Turn ON Threshold Range Measured at V _{PP}	V _{TH-low-on}	Turn on for any I _{CLASS} while V _{PP} increases	11.4		13.7	V
Classification Disconnection Minimum Hysteresis Voltage.	V _{HST}	Hysteresis between V _{TH-low-on} and V _{TH-low-off}		1		V
Classification Current Source, Turn OFF Threshold Range Measured at V _{PP}	V _{TH-high-off}	Turn off while V _{PP} increases	20.9		23.9	V
Current limit threshold	I _{CLASS-LIM}		50.0	68	80.0	mA
Input current I _{PP} when classification function is disabled	I _{CLASS-DIS}	Class 0 R _{CLASS} = Open			3.0	mA
Input current I _{PP} when classification function is enabled	I _{CLASS-EN}	Class 1 R _{CLASS} = 133Ω±1%	9.50	10.5	11.5	mA
		Class 2; R _{CLASS} = 69.8 Ω±1%	17.5	18.5	19.5	mA
		Class 3 R _{CLASS} = 45.3 Ω±1%	26.5	28.0	29.5	mA
		Class 4 R _{CLASS} = 30.9 Ω±1%	38.0	40.0	42.0	mA

PRODUCT DATASHEET

Parameter	Symbol	Test Conditions / Comment	PD70101A & PD70201			Units
			Min	Type	Max	
Rclass Voltage			1.142		1.278	V
MARK						
Mark, working range	V_{MARK}	V_{PP} falling edge	4.9		10.1	V
Mark Current	I_{MARK}		0.25		4	mA
ISOLATION SWITCH						
Isolation Switch MOSFET switches from off to $I_{\text{LIM-LOW}}$	$V_{\text{SW-START}}$		36			V
Isolation Switch MOSFET switched off	$V_{\text{SW-OFF}}$		30.5		34.5	V
Startup current limit, $I_{\text{LIM-LOW}}$	$I_{\text{LIM-LOW}}$		130	240	330	mA
VPN_IN to VPN_OUT Threshold voltage for $I_{\text{LIM-LOW}}$ to $I_{\text{LIM-HIGH}}$ switchover	V_{DIFF}	When VPN_{IN} to $\text{VPN}_{\text{OUT}} \leq V_{\text{DIFF}}$, Isolating switch switches over from $I_{\text{LIM-LOW}}$ to $I_{\text{LIM-HIGH}}$.			0.7	V
Over current protection limit current	OCP		1500	1800	2000	mA
Continuous operation load	I_{LOAD}	Isolating switch at $I_{\text{LIM-HIGH}}$ PD70101A PD70201		350 600	450 1123	mA mA
Isolated Switch On resistance @ $I_{\text{LIM-HIGH}}$	SW-RDS _{ON}	Total resistance between VPN_{IN} and VPN_{OUT} Isolating switch at $I_{\text{LIM-HIGH}}$			0.6	Ω
DC/DC CAPACITOR DISCHARGER						
DC/DC input capacitance	C_{IN}	For reference only Guaranteed by design (not tested in production)		220	264	μF
Discharge current.		$7.0\text{V} \leq V_{\text{PP}}$ to $\text{VPN}_{\text{OUT}} \leq 30\text{V}$	22.8	32	50	mA
AT_FLAG						
Output low voltage		$I_{\text{OL}} = 0.75\text{mA}$			0.4	V
		$I_{\text{OL}} = 5\text{mA}$			2.5	V
Leakage current		$V_{\text{ATFLAG}} = 57\text{V}$			1.7	μA
PGOOD						
Output low voltage		$I_{\text{OL}} = 0.75\text{mA}$			0.4	V
		$I_{\text{OL}} \text{ MAX} = 5\text{mA}$			2.5	V
Leakage current		$V_{\text{PGOOD}} = 57\text{V}$			1.7	μA
PD INTERFACE THERMAL SHUTDOWN						
Thermal Shutdown Temperature ¹			180	200	220	$^{\circ}\text{C}$
VAUX (respect to VPN_OUT)						
VAUX Output Voltage Off (leakage current)	VAUX-off	PGOOD = High impedance Load = 1M Ω			1	V

PRODUCT DATASHEET

Parameter	Symbol	Test Conditions / Comment	PD70101A & PD70201			Units
			Min	Type	Max	
VAUX Output Voltage On	VAUX-on	Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	9.5	10.5	11.8	V
Output Current Peak	I_{VAUXP}	Capacitor = 30uF When $T_{LOAD} \leq 5mS$ Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	0		10	mA
Output Continuous Current	I_{VAUXC}	When $T_{LOAD} \leq 10mS$ Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	0		2	mA
VAUX Output Current Limit	I_{VAUX}	Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	10		32	mA
DC-DC Controller						
VCC						
Maximum Input Operating Voltage	VCC				20	V
Input Current	I_{VCC}	$VCC < VCC_UVLO$ or ENABLE = Low.			200	μA
		$VCC > VCC_UVLO$ & ENABLE = High, No Load on PG, SG, VL, and $F_{SW} = 500kHz$.			3	mA
VCC UVLO Rising Threshold	VCC_UVLO	VCC raising edge	8.85	9.15	9.5	V
VCC UVLO Falling Threshold	VCC_UVLO	VCC falling edge	7	7.3	7.6	V
POE PORT INPUT UVLO						
UVLO Threshold	VINS		1.171	1.200	1.229	V
VINS Input Current			-0.1		+0.1	μA
HYST Output High Voltage	HYST- V_{OH}	$I_{SOURCE} = 1mA$	2.8			V
HYST Output Low Voltage	HYST- V_{OL}	$I_{SINK} = 3mA$			0.4	V
INTERNAL LDOs						
+5 V LDO	VL	$IL < 5mA$	4.75	5	5.25	V
-5 V LDO	VH	Reference to VCC		-5		V
SOFT-START						
Soft-start Charging Current ²	I_{SS_CHG}	$R_{FREQ} = 33.2k\Omega$; $V_{SOFTSTART} = 0.5V$	32	36	40	μA
Soft-start Discharging Current	I_{SS_DIS}	$V_{SOFTSTART} = 0.5V$; % of I_{SS_CHG}		10		%
Soft-start Completion Threshold ¹	V_{SS}	% of 1.2V	90		95	%
Soft-start Discharge Completion Threshold ¹	V_{SS}			50		mV
Soft-start Discharge FET On Resistance				50		Ω
Soft-start Discharge FET On Time ¹		1cyc= $1/F_{FREQ}$		32		cyc
SWITCHING FREQUENCY AND SYNCHRONIZATION						
Switching Frequency Range	F_{FREQ}		100		500	kHz

PRODUCT DATASHEET

Parameter	Symbol	Test Conditions / Comment	PD70101A & PD70201			Units
			Min	Type	Max	
Switching Frequency Accuracy ³	F _{FREQ}	R _{FREQ} = 33.2k	285	315	345	kHz
Synchronization Frequency Range	F _{SYNC}	F _{SYNC} > 2x F _{FREQ}	200		1000	kHz
Synchronization Voltage High Threshold	V _{SYNC-HIGH}		2.4		5	V
Synchronization Voltage Low Threshold	V _{SYNC-LOW}				0.8	V
Synchronization Minimum Pulse Width	PW _{SYNC_min}		100			ns
Synchronization Maximum PWM Duty	PW _{SYNC_max}				90	%
Synchronization Input Current	I _{SYNC}		-1.3		+1.3	μA
ERROR AMPLIFIER						
DC Open Loop Gain ¹		R _{LOAD} = 100k	70	100		dB
Unity gain bandwidth ¹	AV _{UGBW}	C _{LOAD} = 10pF	2	5		MHz
Output Sourcing Current		0.2V ≤ V _{COMP} ≤ 1.3V	110		620	μA
Output Sink Current		0.2V ≤ V _{COMP} ≤ 1.3V	145		495	μA
Input Common Mode Range			0		2	V
Feedback Voltage	V _{FB}	COMP shorted to FB.	1.171	1.200	1.229	V
FB Pin Input Current	I _{FB}		-50		50	nA
Output High Clamp	V _{COMP}		1.8	2.1	2.6	V
PWM COMPARATOR						
RCLP Voltage range	V _{RCLP}		0		1	V
LOW POWER MODE (SKIP PULSE MODE)						
Low Power Skip Mode Threshold ^{1,4}		V _{COMP} Rising (% of V _{RCLP}).		95		%
		V _{COMP} Falling (% of V _{RCLP}).		90		%
CURRENT SENSE AMPLIFIER AND CURRENT LIMIT						
Gain		Measure at DC	4.75	5.0	5.25	V/V
Input Common Mode Range			0		2.0	V
Output Rise/Fall time ¹		10% to 90%			75	ns
Blanking Time ¹			50		100	ns
Current Limit Threshold	V _{ILIM_TH}		1.1	1.2	1.3	V
Current Max Threshold	V _{IMAX_TH}		1.7	1.8	1.9	v
OUTPUT DRIVERS						
Primary Gate (PG) High On Resistance	PG Rds _{ONH}			10		Ω
Primary Gate (PG) Low On Resistance	PG Rds _{ONL}			5		Ω

PRODUCT DATASHEET

Parameter	Symbol	Test Conditions / Comment	PD70101A & PD70201			Units
			Min	Type	Max	
Secondary Gate (SG) High On Resistance	SG Rds _{ONH}			10		Ω
Secondary Gate (PG) Low On Resistance	SG Rds _{ONL}			10		Ω
Dead Time – PG low to SG high or SG low to PG high	T _{DEAD}	C _{LOAD} on PG and SG = 1000pF		110		ns
PG Minimum On Time					120	ns
PG Maximum Duty Cycle			44.5		50	%
LOGIC (ENABLE PIN)						
Logic High Threshold			2.0			V
Logic Low Threshold					0.8	V
Input Current			-1		1	μA
PWM CONTROLLER THERMAL SHUT DOWN						
Thermal Shutdown Threshold ¹				157		°C
Threshold Hysteresis ¹				15	30	

Notes:

- 1) Guaranteed by design
- 2) Soft Start Charge Current Equation: $I_{ss_chg} = 1.2V/R_{FREQ}$
- 3) Switching Frequency Equation:

$$Freq = \frac{1}{(90pF \times R_{FREQ}) + 150ns}$$
where Freq is [Hz]
- 4) Low Power Mode Clamp Equation: $V_{CLAMP} = 0.3 * (R_{RCLP}/R_{FREQ})$



**PD70101A / PD70201: IEEE 802.3 af/at
Power Over Ethernet PD Controller**

PD70101A/PD70201 FUNCTIONAL BLOCK DIAGRAM

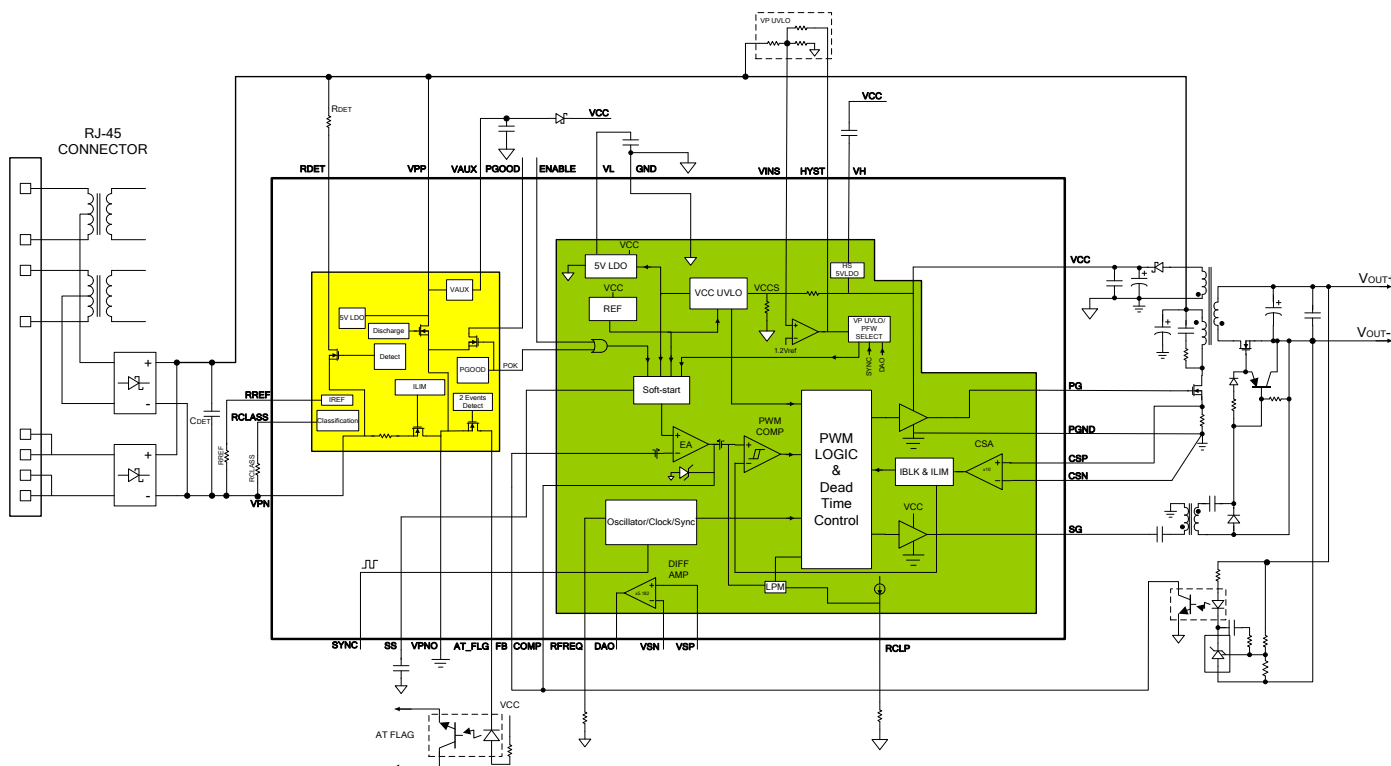


Figure 1: PD70101A/PD70201 Functional Block Diagram (PD70201 shown)

PD70101A/PD70201 PIN DESCRIPTION

Pin	PD70101A Pin Name	PD70201 Pin Name	Description
1	RDET	RDET	Valid Detection Resistor: Connect a 24.9kΩ, 1% resistor from this pin to VPP
2	PGOOD	PGOOD	Open Drain Output (active low): This flag is generated to indicate the power rails (VPN_OUT) are ready
3	RREF	RREF	Bias current resistor for the PD Interface.
4	RCLASS	RCLASS	Power Classification Setting: Connect external class resistor between this pin and VPN_IN.
5	VPN_IN	VPN_IN	VPort Negative Input: Connected to the isolating switch input N-channel MOSFET source.
6	N/C	N/C	Not Used
7	N/C	AT_FLAG	Open Drain Output (active low): This flag indicates if the chip detects an IEEE 802.3at compliant PSE.
8	VPN_OUT	VPN_OUT	VPort Negative Output: Connected to the isolating switch output. N-channel MOSFET Drain.
9	N/C	N/C	Not Used
10	ENABLE	ENABLE	Logic level Enable input for DC-DC controller. Pulling this pin to VL turns on the DC-DC controller. This allows the DC-DC controller to be turned on without power to the PD interface.
11	VINS	VINS	VPP input voltage sensing for UVLO comparator. Connect to an external resistor divider from VPP to GND. Threshold is 1.2V reference.
12	HYST	HYST	Output of the VINS/UVLO comparator. This pin is used for VPP UVLO hysteresis programming.
13	SYNC	SYNC	External Clock synchronization for the DC-DC controller. Connect an external clock as defined in the EC table to this pin to synchronize the DC-DC converter switching frequency to this clock. PG rising edge is synchronized with the clock rising edge.
14	RFREQ	RFREQ	DC-DC Switching Frequency Setting. Connect a resistor from this pin to GND to set the switching frequency
15	SS	SS	Soft-start: Connect a capacitor from this pin to GND to set the soft-start time of the DC-DC converter. This capacitor is charged with an internal current source to 1.2V
16	RCLP	RCLP	Low Power Mode Clamp. Connect a resistor from this pin to GND to program the LPM clamping voltage or connect this pin to GND to disable LPM.
17	VSN	VSN	Differential Amplifier's negative input. Connect this to the junction of a resistor divider from Vo- to GND for the Direct Buck converter application
18	VSP	VSP	Differential Amplifier's positive input. Connect this to the junction of a resistor divider from Vo+ to GND for the Direct Buck converter application

PD70101A/PD70201 PIN DESCRIPTION

Pin	PD70101A Pin Name	PD70201 Pin Name	Description
19	COMP	COMP	Error Amplifier Output. Short to FB pin when driven directly with an optoisolator for Isolated DC-DC Converter. Connect to FB via RC compensation networks for Non-Isolated Direct Buck Converter.
20	DAO	DAO	Differential Amplifier Output. Connect to FB (externally) via a 1.2k Ω resistor for Non-Isolated Direct Buck Converter.
21	FB	FB	Inverting Input of the Error Amplifier. Connect to SS for Isolated DC-DC. Connect to RC compensation networks for Non-isolated DC-DC
22	GND	GND	This is Analog GND. Connect to a local AGND plane. Soft-start capacitor and the frequency setting resistor return to this local GND plane.
23	VL	VL	5V (GND reference) internal LDO Output. Connect a 1 μ F or higher ceramic cap from VL to GND.
24	SG	SG	Secondary Gate Driver. Output is the compliment of PG output. Leave open (NC) if not used. SG is low when in Low Power Skip Mode.
25	PGND	PGND	This is the Power Ground. Connect to a local PGND plane. Input, VCC decoupling capacitors, PG and SG drivers, Primary current sense resistor return to this PGND
26	CSN	CSN	Negative Input of the Current Sense Amplifier. Kelvin connect to the PGND side of the primary current sense resistor
27	CSP	CSP	Negative Input of the Current Sense Amplifier. Kelvin connect to the Non-PGND side of the primary current sense resistor
28	PG	PG	Primary Gate Driver. Connect to the gate of the primary side Power MOSFET, directly or via a resistor
29	VH	VH	5V High side (VCC reference) internal LDO Output. Connect a 0.1 μ F or higher ceramic cap from VH to VCC.
30	VCC	VCC	Input Supply to the DC-DC Controller. Connect a 4.7 μ F or higher ceramic capacitor from this pin to PGND. Alternately an parallel combination of 1 μ F ceramic and an greater than 10 μ F electrolytic capacitor can be used.
31	VAUX	VAUX	Auxiliary voltage reference to VPN_OUT; this voltage can be used for DC-DC startup when operated with a bootstrapped voltage source. For applications with POE power only connect directly to VCC; for applications using multiple power sources (such as a wall adaptor), connect to VCC pin through a small, low current, 30V rated diode.
32	VPP	VPP	This is the positive terminal of the POE input port. Connect to the positive terminal of the input bridges at the C _{DET} positive side
EP	Exposed Pad	Exposed Pad	Thermal Pad; electrically connected to VPN_IN. For proper thermal management should be tied to a large copper fill or plane that is electrically connected to VPN_IN.



Microsemi

PD70101A & PD70201

PD70101A / PD70201: IEEE 802.3 af/at Power Over Ethernet PD Controller

PRODUCT DATASHEET

TYPICAL APPLICATIONS

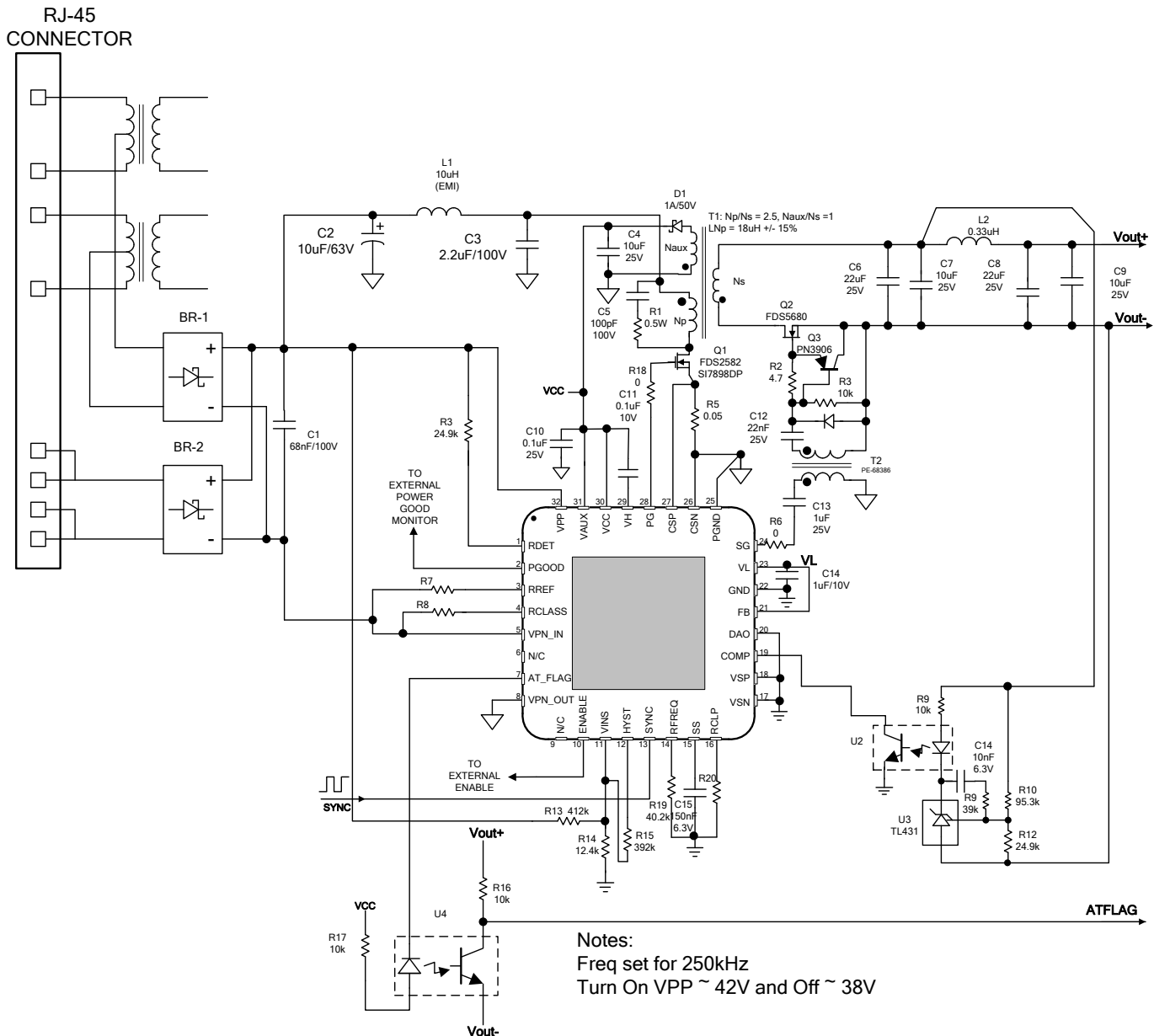


Figure 2: 12V/2A Output Isolated Fly-back with Secondary Synchronous Rectification



THEORY OF OPERATION

DETAIL DESCRIPTION

PD70101A/PD70201 IC integrates IEEE 802.3af/at compliant PD Front-End functions including Detection, Physical Layer Classification, Two-Events Classification (PD70201 only), Power Good, Soft Start Current Limiting, Over-Current Protection, and Bulk Capacitor Discharge with a PWM controller. The integrated PWM controller function provides a PWM controller solution with a minimum requirement of external components.

DETECTION

IEEE 802.3af/at compliant detection is provided by means of a 24.9K Ω resistor connected between VPP and RDET pin. RDET pin is connected to VPN_IN via an open drain MOSFET with a maximum specified RDS_{ON} of 50 Ω . Internal logic monitors VPP to VPN_IN and connects the RDET pin to VPN_IN when the rising VPP to VPN_IN voltage is between 1.1V and 10.1V. When rising VPP to VPN_IN voltages exceed 10.1V, the MOSFET is switched off. Once above 10.1V, falling VPP to VPN_IN voltage between 2.45V and 4.85V will reconnect RDET pin to VPN_IN.

PHYSICAL LAYER CLASSIFICATION

Physical Layer (hardware) Classification per IEEE 802.3af/at is generated via a regulated reference voltage of 1.2V, switched onto the RCLASS pin. Internal logic monitors the VPP to VPN_IN voltage and connects the 1.2V reference to RCLASS pin at a rising VPP to VPN_IN voltage threshold between 11.4V and 13.7V. Once VPP to VPN_IN has exceeded the rising threshold, there is a 1V typical hysteresis between the VPP rising (turn-on) threshold and the VPP falling (turn-off) threshold.

The 1.2V reference stays connected to the RCLASS pin until the VPP to VPN_IN rising voltage exceeds the upper turn-off threshold of 20.9V to 23.9V. The 1.2V reference voltage is disconnected from the RCLASS pin at VPP to VPN_IN voltages above the upper threshold.

Classification current signature is provided via a resistor connected between RCLASS pin and VPN_IN. The classification current is therefore the current drawn by the PD70101A/PD70201 IC during the classification phase, and is simply the 1.2V reference voltage divided by the RCLASS resistor value. The maximum current available at the RCLASS pin is current limited to 68mA (typical).

TWO-EVENTS DETECTION AND AT FLAG

The PD70201 IC provides IEEE 802.3at Type 2 compliant detection of the "Two Events Classification Signature", and generation of the AT flag. This feature is available on the PD70201 IC only.

Simply put, the "Two Events Classification Signature" is a mean by which an IEEE 802.3at Type 2 Power Source can inform a compliant Power Device (PD) that it is AT Type 2 compliant, and as such is capable of providing AT Type 2 power levels.

The Power Source communicates the Type 2 compliant signature by toggling the VPP to VPN_IN voltage twice (2 "events") during the Physical Layer Classification phase. The VPP to VPN_IN voltage is toggled from the Physical Layer Classification's voltage level (13.5V to 20.9V) down to a voltage "Mark" level. Voltage "Mark" level is specified as a VPP to VPN_IN voltage of 4.9V to 10.1V.

PD70201 IC recognizes a VPP to VPN_IN falling edge from Classification level to Mark level as being one event of the Two-Events Signature. If two such falling edges are detected, PD70201 will assert AT flag by means of an open drain MOSFET connected between AT_FLAG pin and VPN_OUT.

AT_FLAG pin is active low; a low impedance state between AT_FLAG and VPN_OUT indicates a valid Two-Events Classification Signature was received, and the Power Source is AT Type 2 compliant.

AT_FLAG MOSFET is capable of 5mA of current and can be pulled up to VPP.

SOFT START AND INRUSH CURRENT PROTECTION

PD70101A/PD70201 IC contains an internal isolation switch, that provides ground isolation between Power Source and PD application during Detection and Classification phases. The isolation switch is a N-channel MOSFET, wired in a common source configuration where the MOSFET's Source is connected to Power Source ground at VPN_IN, and the MOSFET's Drain is connected to application's primary ground at VPN_OUT.

THEORY OF OPERATION

Internal logic monitors VPP to VPN_IN voltage and keeps the MOSFET in a high impedance state until VPP to VPN_IN voltage reaches turn-on threshold of 36V to 42V. Once VPP to VPN_IN voltage exceeds this threshold, the MOSFET is switched into one of two modes.

Mode into which the MOSFET is switched is determined by the voltage developed across the MOSFET, or put another way, the VPN_OUT to VPN_IN differential voltage. Two modes are defined below:

Isolation Switch Modes		
VPN_OUT to VPN_IN	Mode	Description
$\geq 0.7V$	Soft Start Mode	Limits VPN_OUT current to 240mA (typical)
$\leq 0.7V$	Normal Operating Mode	Limits VPN_OUT current to 1.8A (typical)

By controlling the MOSFET current based on VPN_OUT to VPN_IN voltage, inrush currents generated by fully discharged bulk capacitors can be limited. This method limits current to a maximum of 350mA, compliant with IEEE 802.3af/at specification.

Soft Start current limiting is required to reduce occurrences of voltage sag at the PD input during device power-up. A comparison is shown in Figure 3.

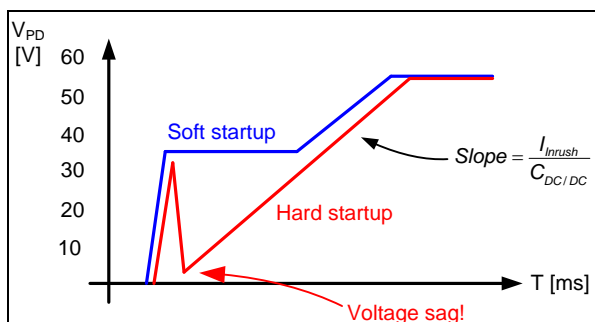


Figure 3. Comparison of input voltages without Soft Start (Hard startup), and with Soft Start (Soft startup).

Once bulk capacitance has charged up to a point where VPN_OUT to VPN_IN differential voltage is less than 0.7V, the isolation MOSFET is switched into normal operating mode with MOSFET current limit set at 1.8A (typical), to provide overcurrent protection.

PD70101A and PD70201 ICs are different in their respective isolation MOSFET's continuous current handling capability:

PD70101A: 450mA (max.)

PD70201: 1123mA (max.)

An adequate heatsink for the PD70101A/PD70201 IC's exposed pad must be provided to achieve these current levels without damaging the IC. A large, heavy copper fill area and/or a heavy ground plane with Thermal Vias is recommended.

Internal logic monitoring VPP to VPN_IN will place the isolation switch MOSFET in a high impedance state if voltage between VPP and VPN_IN drops below 31V to 34V.

OVER-CURRENT PROTECTION

An over-current protection is provided on the PD70101A/PD70201 IC using the Isolation Switch MOSFET, which limits the VPN_OUT current to 1.8A during normal operation. See previous description of Soft Start.

POWER GOOD

During Soft Start mode, the PD70101A/PD70201 IC monitors VPN_OUT to VPN_IN differential voltage. When this voltage is less than 0.7V (max.), the IC enters normal operation mode and the isolation switch current limit is increased to 1.8A (typical). At this same 0.7V (max.) threshold the Power Good signal is asserted by means of an open drain MOSFET between PGOOD and VPN_OUT.

PGOOD pin is active low; a low impedance state between PGOOD and VPN_OUT indicates the Soft Start mode has finished and the isolation switch has transitioned into normal operating mode.

PGOOD MOSFET can handle current of 5mA and can be pulled up to VPP.

THEORY OF OPERATION

START-UP SUPPLY

PD70101A/PD70201 IC provides a 10.5V (typical) regulated output used as a start-up supply for the integrated DC/DC controller when V_{CC} is provided via a bootstrap winding. This regulated supply is available at VAUX pin, and is referenced to VPN_OUT pin. The VAUX start-up supply is current-limited at 10mA (min.).

For stability, the start-up regulator requires a minimum of 4.7 μ F ceramic capacitor connected directly between VAUX and PGND pins (most applications will connect PGND to VPN_OUT).

For applications where power to the DC-DC controller is provided by POE only, the VAUX pin is connected directly to VCC. For applications which have alternate power sources (such as a wall adaptor), the VAUX pin output is connected to the VCC pin through a series diode. This diode is typically a low current diode with a 30V rating.

PD INTERFACE THERMAL PROTECTION

Both PD70101A and PD70201 IC contain temperature sensors which individually monitor both the isolation MOSFET and the Classification Current Source for over temperature conditions. In case of an overtemperature condition, the sensor will activate protection circuitry which will disconnect its respective monitored function.

BULK CAPACITOR DISCHARGE

The bulk capacitor discharge circuitry eliminates the need to place a diode in series with the VPP line to prevent an application's bulk capacitance from discharging through the detection resistor and the isolation switch MOSFET's body diode. Discharge current through the detection resistor can cause failure of the detection signature in cases where a PD is connected and the bulk capacitance is not fully discharged.

During normal operation, PD70101A/PD70201 IC continuously monitors voltage at VPP to VPN_IN. Should VPP to VPN_IN voltage fall below isolation switch turn-off threshold (31V to 34V), isolation switch MOSFET is immediately placed in a high-impedance state. At this point the internal logic monitors the voltage at VPP to VPN_OUT.

If VPP to VPN_OUT voltage is between 1.5V to 32V, a 23mA (min.) constant current source is connected across the VPP and VPN_OUT pins. This constant current source provides bulk capacitor discharge. A 220 μ F bulk capacitance can be discharged from 32V to 1.5V in a maximum period of 292ms.

DC-DC START-UP

The DC-DC controller starts up when it receives the PGOOD high signal from the Front End, or ENABLE goes high provided that VCC UVLO have passed. When the PGOOD signal or ENABLE goes high, the start up sequence begins with ramping up the SS pin from GND to 1.2V. For isolated applications the output voltage may reach the maximum level before the SS reaches 1.2V, depending on the output loading condition. In applications with lighter loads, the output reaches regulation level sooner than in heavy loads, as in this mode the SS voltage directly controls the peak inductor current; hence the energy is delivered to the load. The external secondary error amplifier regulates the output voltage and controls the peak inductor current via the opto-coupler across the isolation barrier. For non-isolated applications, because the internal error amplifier is used to close the regulation loop, the output reaches the regulation level when SS reaches 1.2V.

An additional internal offset is added to the FB to ensure that COMP does not reach its upper limit because of amplifier input offset. This offset is removed (slowly to avoid overshoot) when the SS ramp is complete.

Low Power Mode (refer to Low Power Mode Operation) is not supported during SS ramp as it is not necessary.

CURRENT LIMIT AND SHORT CIRCUIT PROTECTION

The DC-DC converter is a peak current mode controller; an internal current sense amplifier with a gain of 5 monitors the voltage across an external current sense resistor and regulates the output based on the current through the resistor. If the output of the internal current sense amplifier reaches 1.2V, the converter will truncated the PWM output, and thus limit the output current.

THEORY OF OPERATION

If the output of the internal current sense amplifier reaches 1.8V, the controller enters hiccup mode by discharging the SS capacitor with a constant current that equals 10% of the charging current during ramp up.

This discharge continues until $V_{SS} = 50 \text{ mV}$ where an internal $\sim 50\Omega$ MOSFET connected to SS turns on for 25 clock cycles to ensure the SS capacitor fully discharges to GND before ramping back up and restart. The converter will exit the hiccup mode when the over current condition is removed.

LOW POWER MODE OPERATION

The devices offer a pulse skipping operation for light load condition, referred as Low Power Mode (LPM), to improve the efficiency of light load operation by reducing the power dissipation especially in high frequency switching. Using an external resistor from RCLP pin to GND, the user can program the output power when the unit enters pulse skipping.

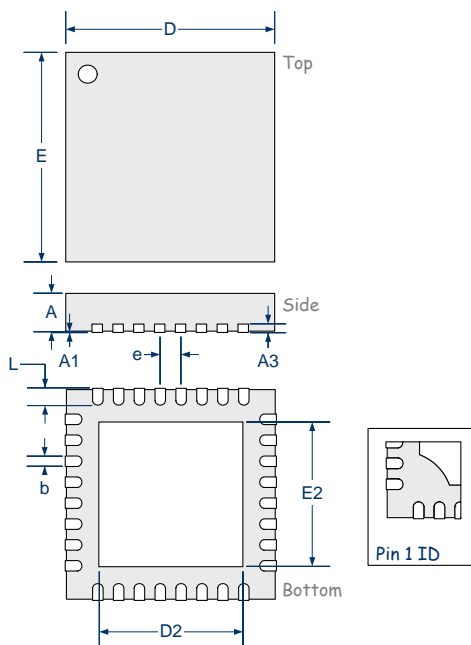
Pulse skipping mode is disabled until SS ramp is completed, regardless of the LPM status.

INPUT (VPP & VCC) UNDER VOLTAGE LOCK OUT

The PD interface circuit offers an internal PGOOD signal that can be used to start the DC-DC converter; however the threshold of the PGOOD is fixed at $VPN_OUT - VPIN_IN \leq 0.7V$. This may not fit all possible applications. Therefore the device offers an option to have a programmable UVLO which is tied to level of $VPP - VPIN_OUT$, plus a programmable hysteresis. The voltage developed across a simple resistor divider is sensed at VINS, and will enable/disable the PWM controller at a nominal 1.2V threshold. A third resistor connected between VINS and HYST pins allows programmable hysteresis. This feature enables the end user to tailor to any desired systems application's requirement for turn on and turn off time. In addition to the VPP sensing for UVLO, the devices also have VCC UVLO to ensure that the PWM controller is always properly powered during operation. These features provide robust solutions under various systems disturbances.

EXTERNAL ENABLE

The PD interface circuit provides an internal PGOOD signal that is used to enable the DC-DC converter when powered by the POE input; however for applications that require input power from a wall adaptor, the internal PGOOD signal is not functional. For these applications an external enable input is provided, allowing a non-POE power source (such as a wall adaptor) the ability to start the DC-DC converter. The Enable pin is active high, and is driven by a 5V maximum signal referenced to GND. When the DC-DC converter is powered by the PD interface (POE power), the Enable pin will not disable the controller. It may be tied to ground or left floating when not used.

LQ
32-Pin 5x5 mm QFN


DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0	0.05	0	0.002
A3	0.20 REF		0.008 REF	
b	0.18	0.30	0.007	0.012
D	5.00 BSC		0.197 BSC	
D2	3.30	3.60	0.130	0.142
E	5.00 BSC		0.197 BSC	
E2	3.30	3.60	0.130	0.142
e	0.50 BSC		0.02 BSC	
L	0.30	0.50	0.012	0.020

Note:

Dimensions do not include protrusions; these do not exceed 0.155 mm (.006") on any side. Lead dimension shall not include solder coverage.



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Revision History

Revision Level / Date	Para. Affected	Description
1.0 Sep 25 2011		Production Data Sheet release
1.1 Feb 2012		Updated Document Formatting and Updated Address Footer
1.2 Jun 25 2012		Update Switching Frequency Accuracy spec limits and equation in note 3.

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Cat. Num: DS_PD70101A_PD70201

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9